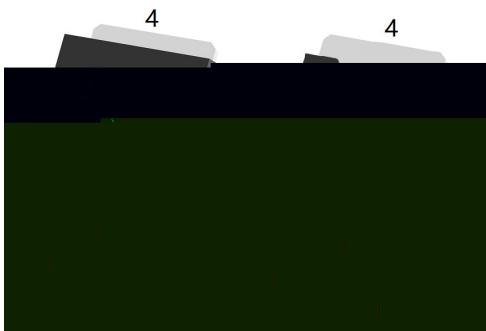
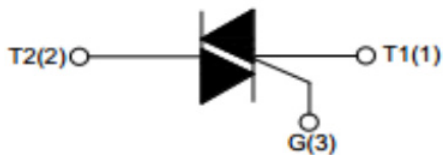


TO-252

Triac in a TO-252 Plastic Package.

Medium current triac, Low on state voltage drop,High reliability and stability,Low thermal resistance, HF Product.

Suitable for general purpose AC switching .Such as static relays,heating regulation,induction motor starting circuits,motor speed controllers,etc.

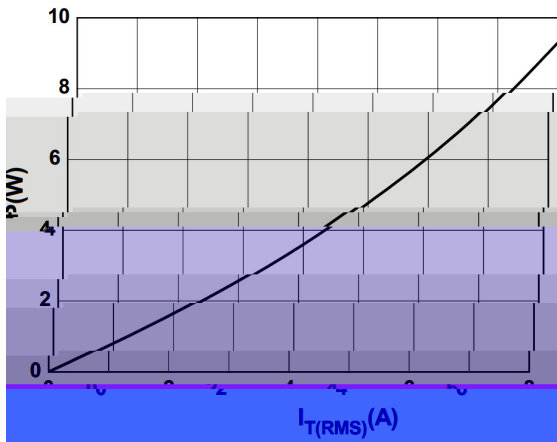
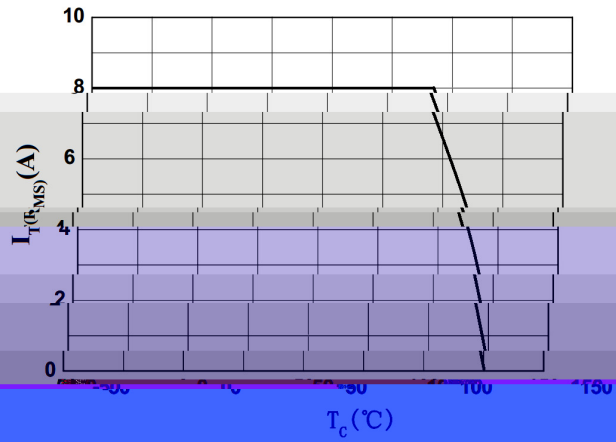
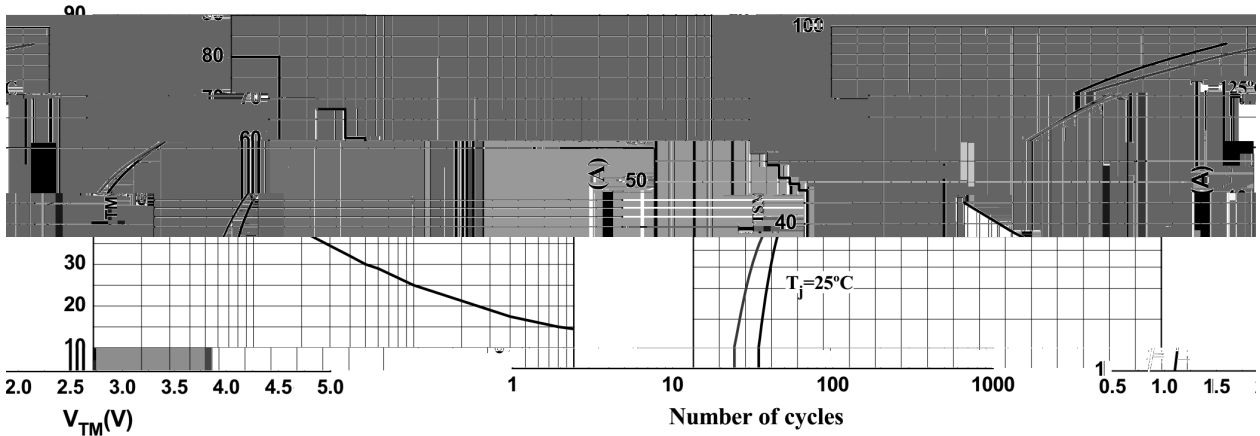


PIN1 Main Terminal 1 PIN 2 4 Main Terminal 2 PIN 3 Gate

See Marking Instructions.

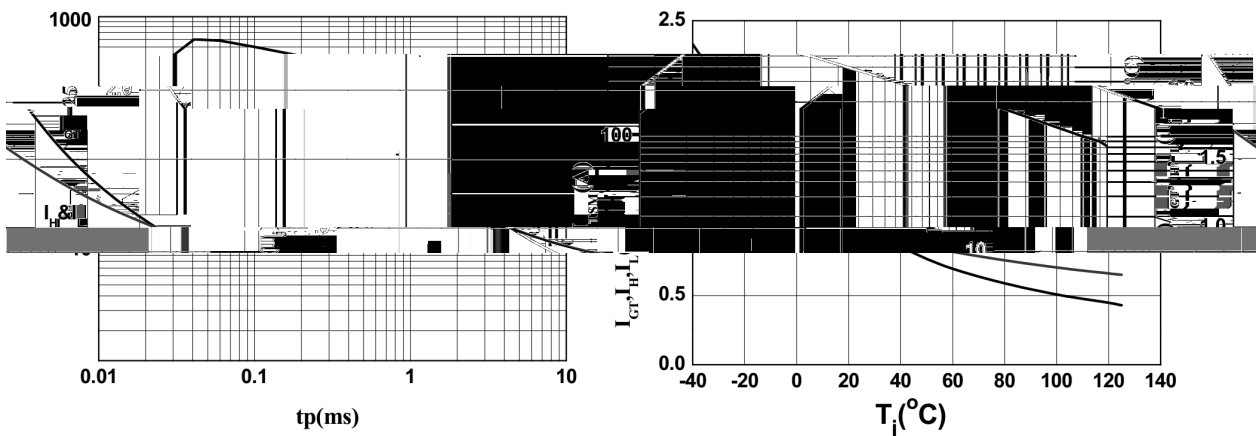
Parameter	Symbol	Rating	Unit
Repetitive peak off-state/reverse voltages($T_j=125$)	V_{DRM}/V_{RRM}	800	V
RMS on-state current($T_C=110$)	$I_{T(RMS)}$	8	A
Non repetitive surge peak on-state current(full cycle, $T_j=25^\circ\text{C}$)	$I_{TSM}(t=20\text{ms})$	80	A
I^2t value for fusing($T_j=25$)	$I^2t_{(tp=10\text{ms})}$	36	A^2s
Critical rate of rise of on-state current ($I_G = 2I_{GT}$, $f=120\text{Hz}$ $T_j=125$)	dI/dt I-II-III	50	$\text{A}/\mu\text{s}$
Peak gate current($t_p = 20\mu\text{s}$ $T_j=125$)	I_{GM}	4.0	A
Average gate power dissipation($T_j=125$)	$P_{G(AV)}$	1	W
Operating junction temperature range	T_j	-40 125	
Storage junction temperature range	T_{stg}	-40 150	
Junction to ambient(AC)	$R_{th(j-a)}$	100	/W
Junction to case for(AC)	$R_{th(j-c)}$	3.1	

Symbol	Test Conditions	Quadrant	Value		Unit
I_{GT}	$V_D=12\text{V}$ $R_L=30$	I-II-III	Max.	35	mA
V_{GT}	$V_D=12\text{V}$ $R_L=30$	I-II-III	Max.	1.3	V
V_{GD}	$V_D=V_{DRM}$ $R_L=3.3\text{K}$ $T_j=125$	I-II-III	Min.	0.2	V
I_L	$I_G=1.2I_{GT}$	I-III	Max.	50	mA
		II		60	
I_H	$I_T=100\text{mA}$		Max.	35	mA
(dV/dt)	$V_D=67\%$ V_{DRM} Gate Open	$T_j=125$	Min.	400	$\text{V}/\mu\text{s}$
V_{TM}	$I_{TM} = 11\text{A}$ $t_p=380\mu\text{s}$	$T_j=25$	Max.	1.55	V
I_{DRM}	$V_D=V_{DRM}$ $V_R=V_{RRM}$	$T_j=25$		10	μA
I_{RRM}		$T_j=125$		1	mA

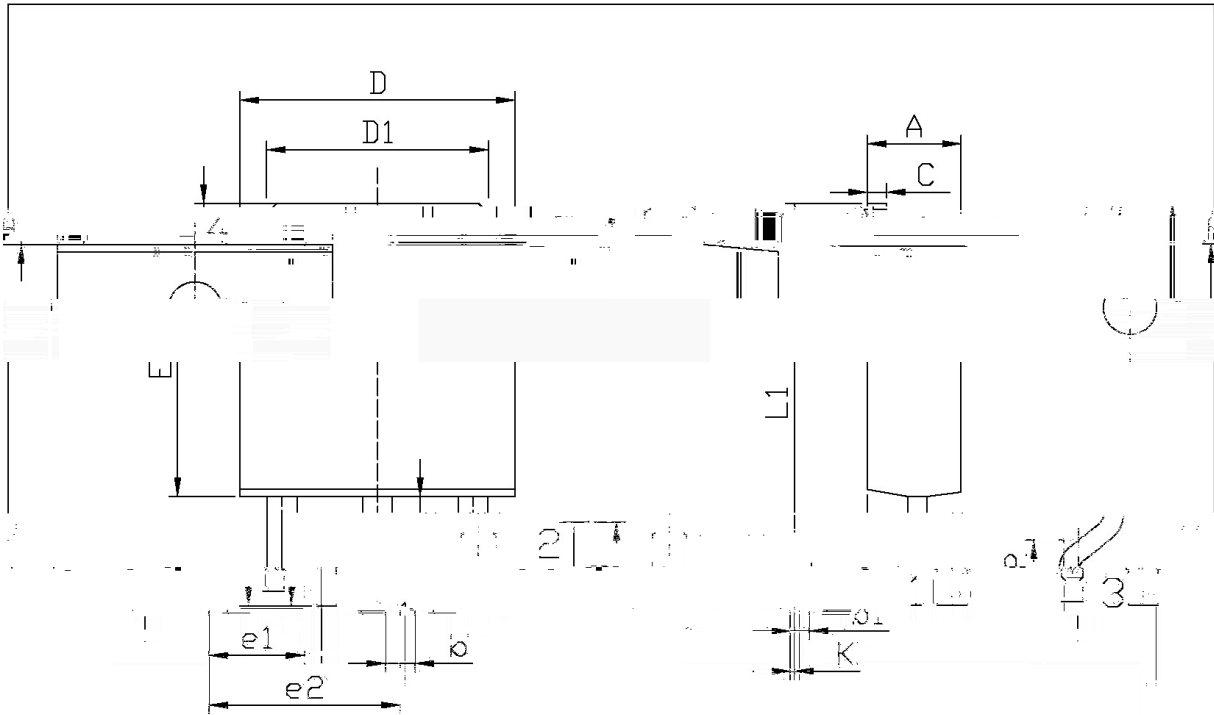

FIG.1 Maximum power dissipation versus RMS on-state current

FIG.2: RMS on-state current versus case temperature

FIG.3: Surge peak on-state current versus number of cycles

4: On-state characteristics

FIG.4


FIG.5: Non-reciprocating surge peak on-state current (for a sinusoidal pulse with width $t_p=50\mu s$, and corresponding value of $I_{T1}(dI/dt<100A/\mu s)$)

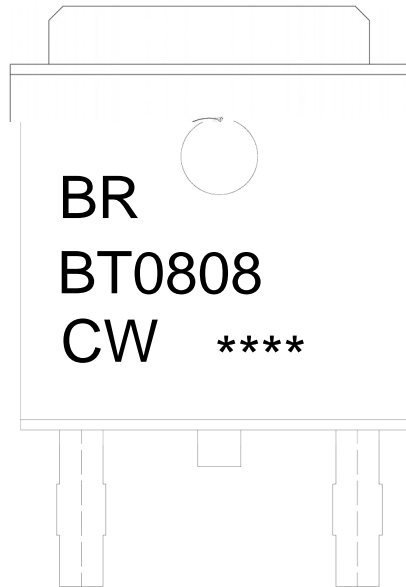
I_T (A) is the surge current, holding current versus junction temperature



单位: mm

Symbol	Dimensions In Millimeters		Symbol	Dimensions In Millimeters	
	Min	Max		Min	Max
A	2.20	2.40	E	5.95	6.25
B	0.95	1.25	e1	2.24	2.34
b	0.50	0.90	e2	4.43	4.73
b1	0.45	0.55	L1	9.45	9.95
C	0.45	0.55	L2	1.25	1.75
D	6.45	6.75	L3	0.60	0.90
D1	5.10	5.50	K	0.00	0.10

TQ-252



BR

BT0808

CW

I_{GT}

Note:

BR: Company Code

BT0808: Product Type Code

CW: I_{GT} Bracket Code

****: Lot No. Code, code change with Lot No

